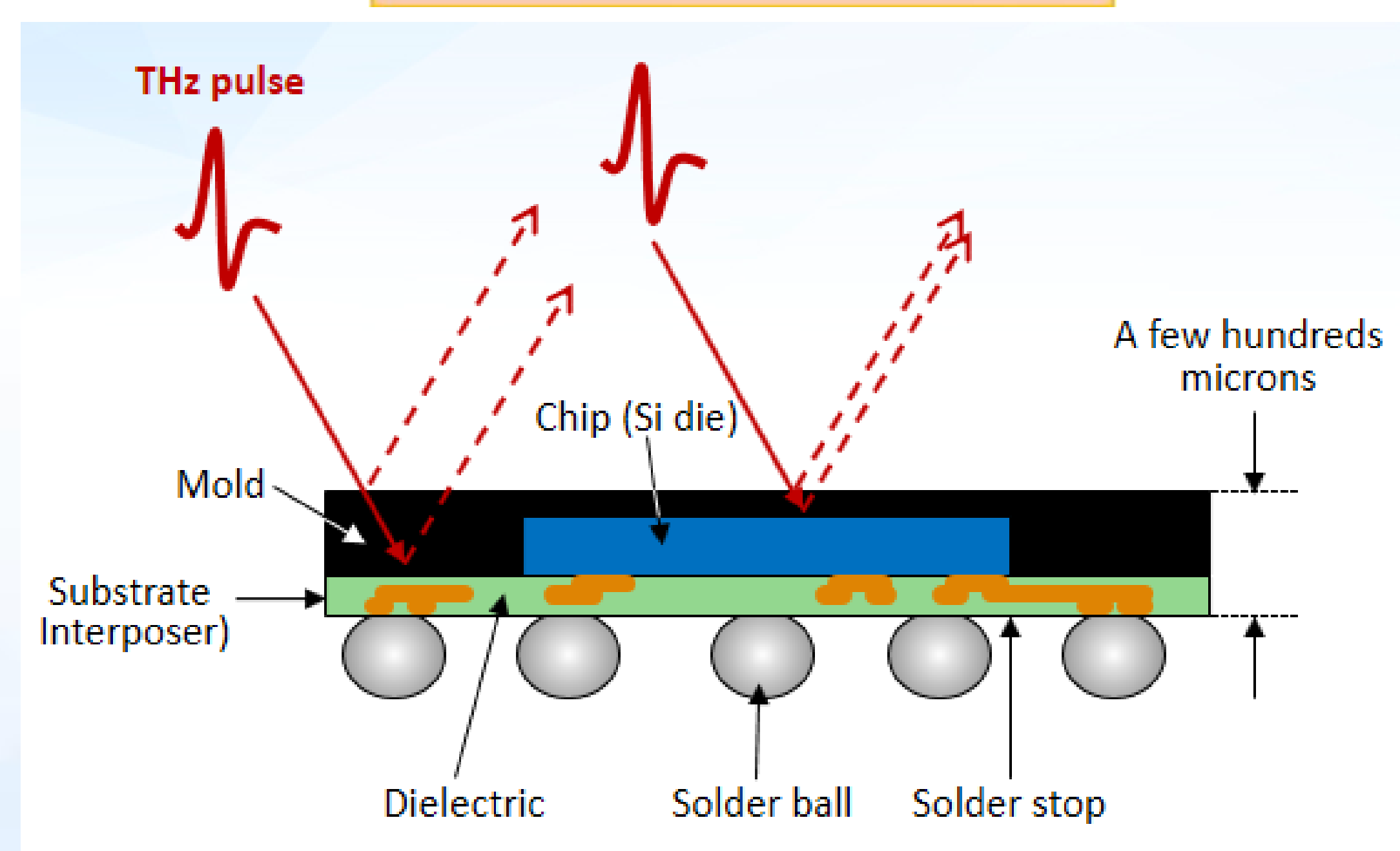
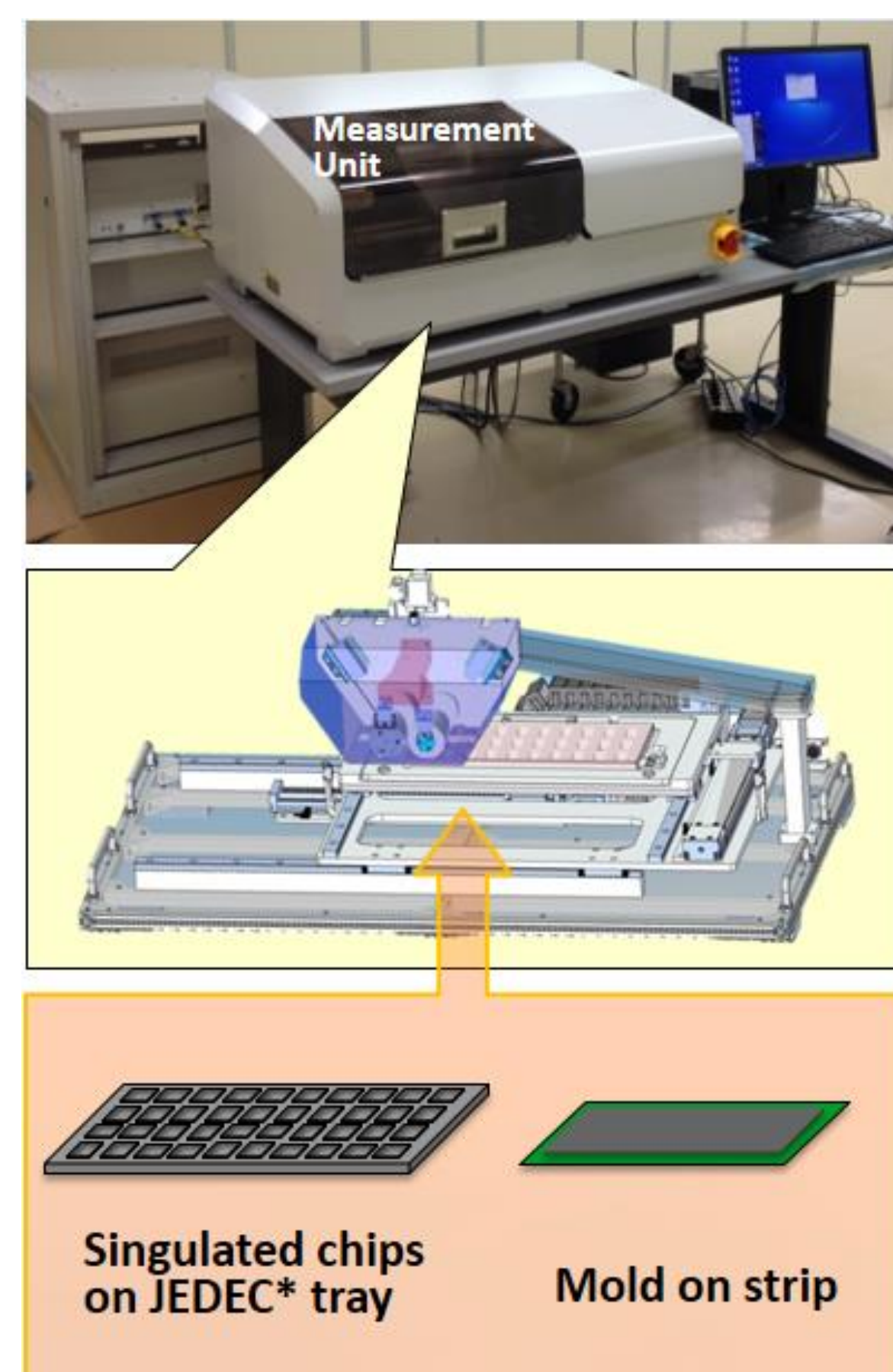


# Examination of Advanced Technologies in Characterization, Diagnostics, and Verification at Different Stages in the Manufacturing Lifecycle of Packaged IC Devices

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## Mold Characterization THz Time of Flight

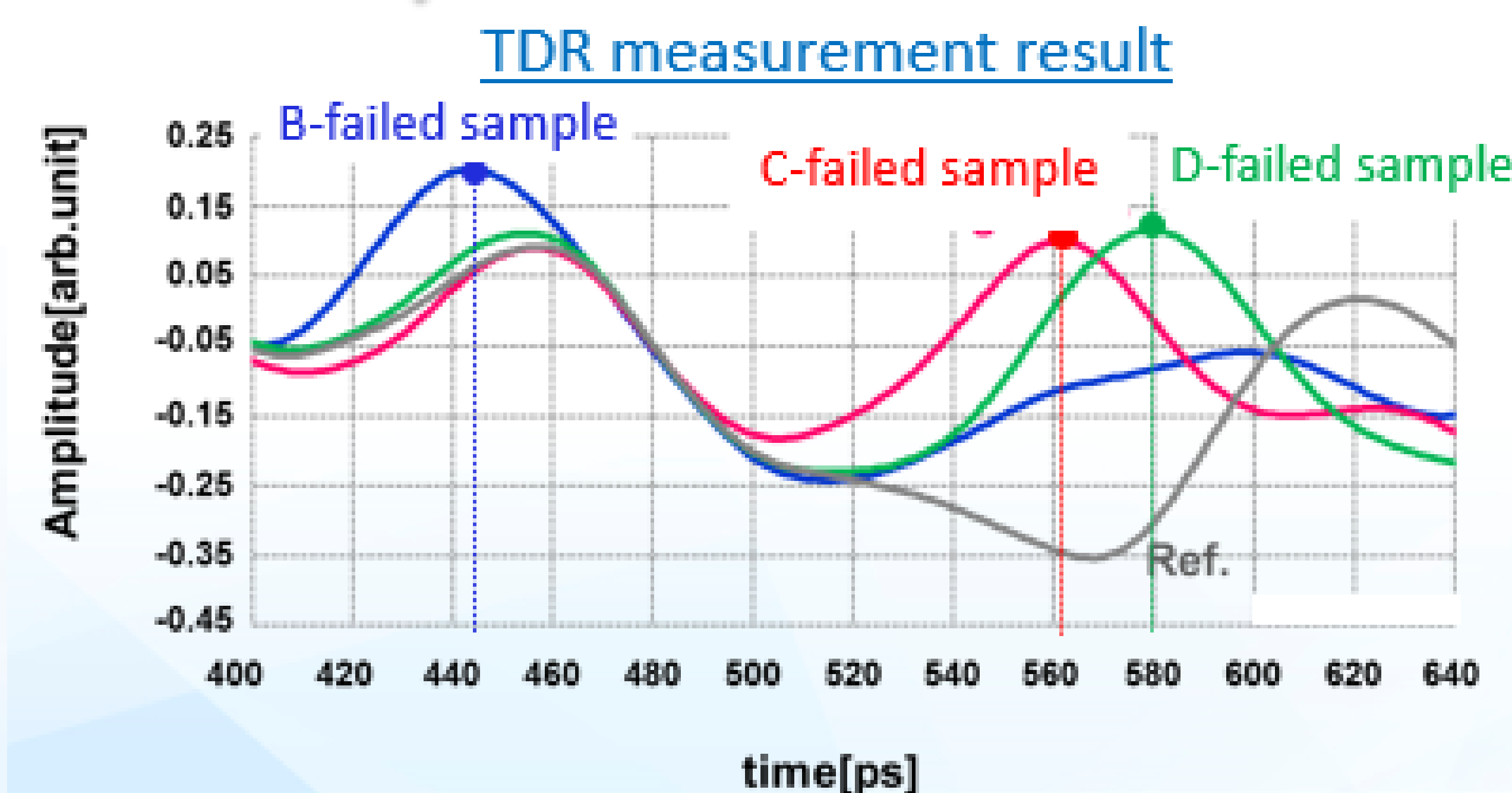
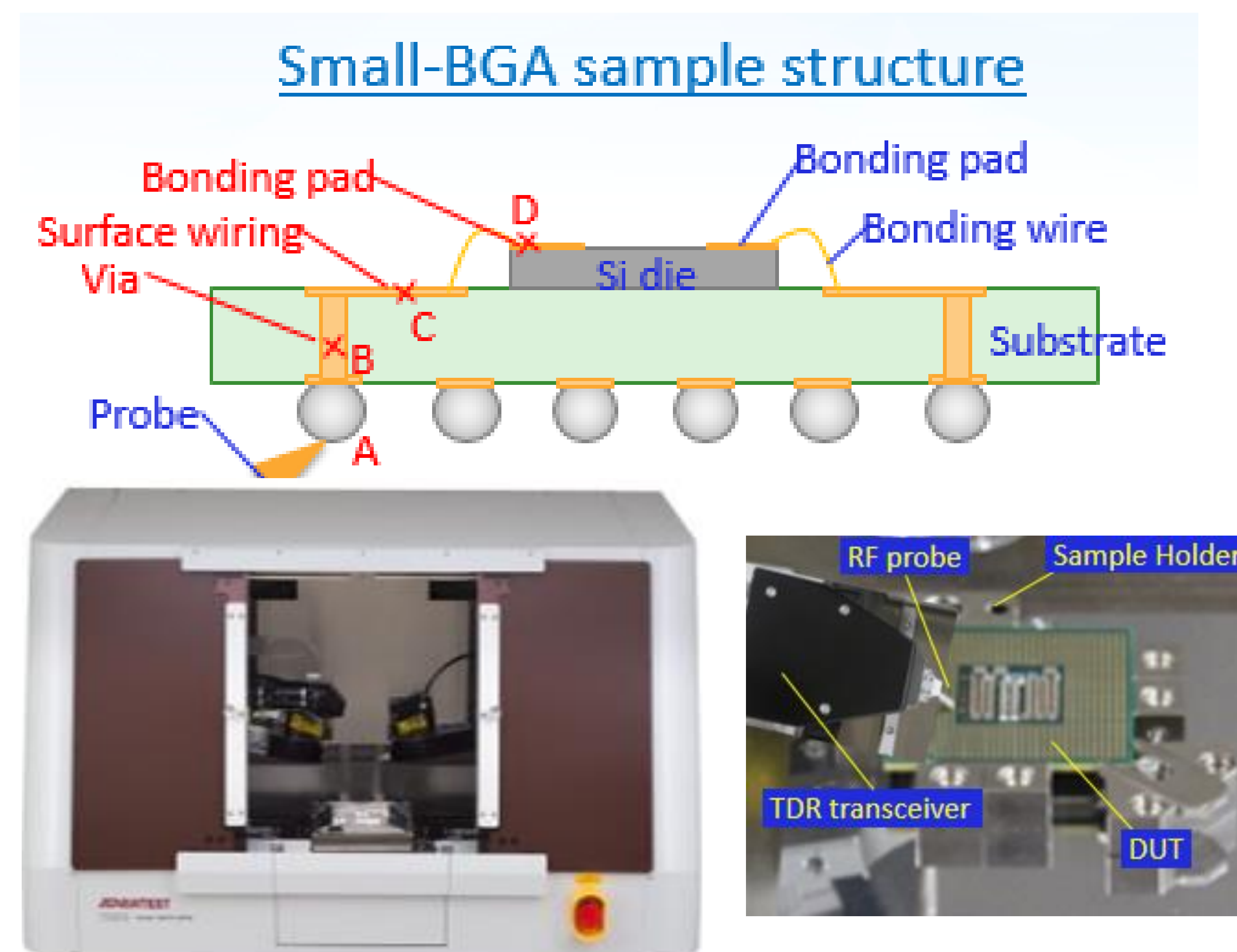
Non-destructive IC mold metrology is needed in factory environment. Terahertz wave penetrates dielectric, reflecting from material interfaces and providing time-of-flight distance allowing thickness calculation. Manufacturing process is improved.



Mold Thickness Accuracy 3μm

## Electrical Diagnostics THz TDR

High speed optical signal is converted to electrical and used for fault isolation by time domain reflectometry. Resolution exceeds conventional methods, useful for advanced packaging failure analysis.



Fault Isolation Accuracy 5μm

## System Level Test Endurance & Production

Endurance Test ensures device design and manufacturing process meet reliability claims. Production test ensures that a particular unit was manufactured to specification. Endurance test requires both thermal accuracy and consistency. Production test most critical to meet the minimum high temperature

$$\text{Stress Test Time} \propto \frac{1}{\text{Stress Temperature}}$$

Endurance test requires thermal accuracy and stability

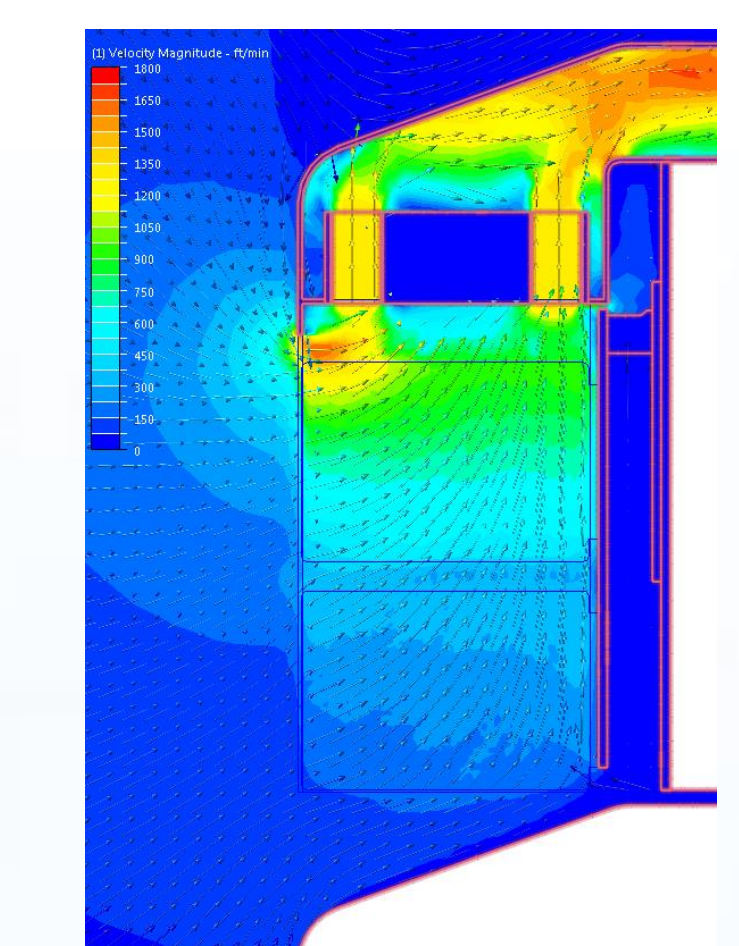
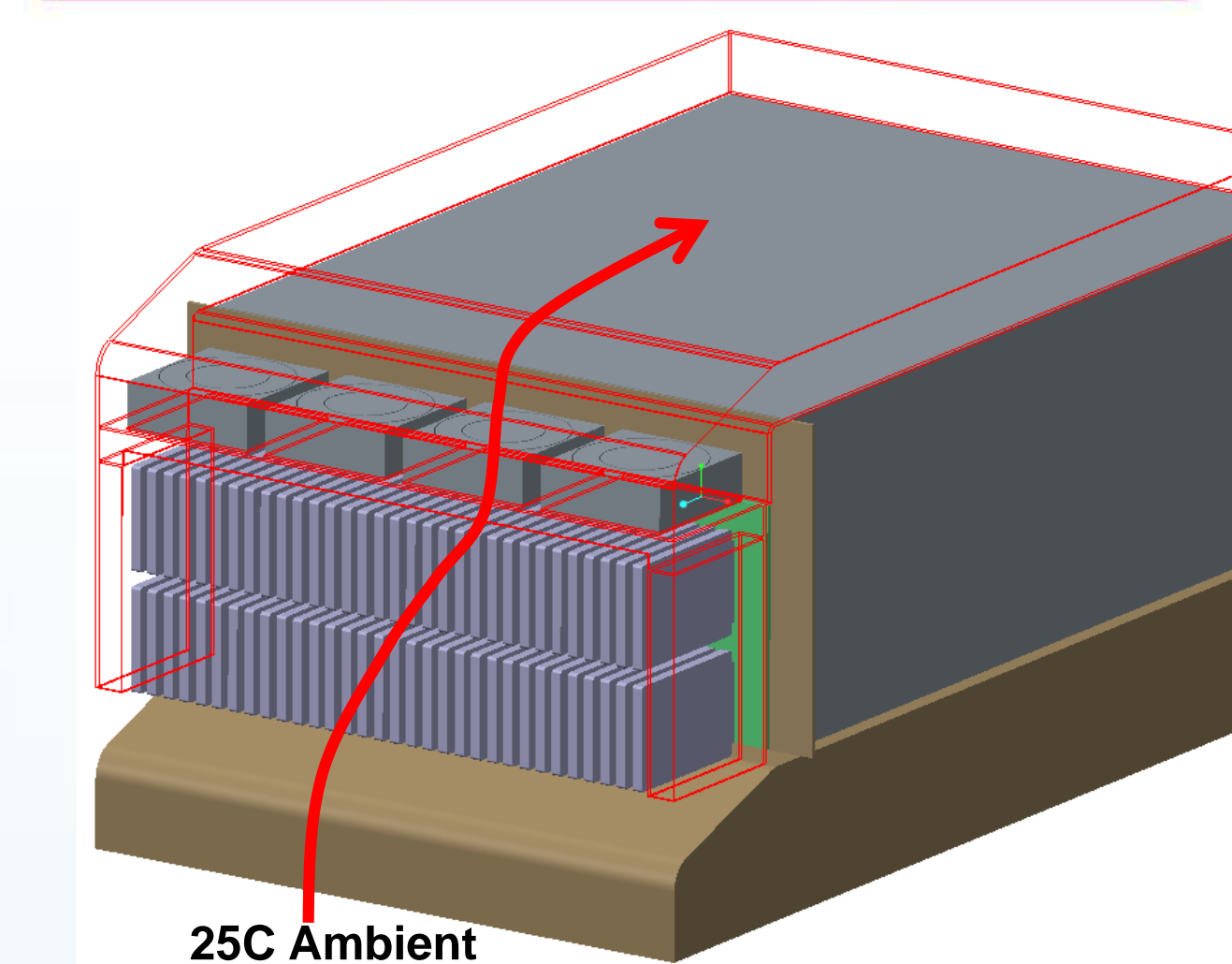
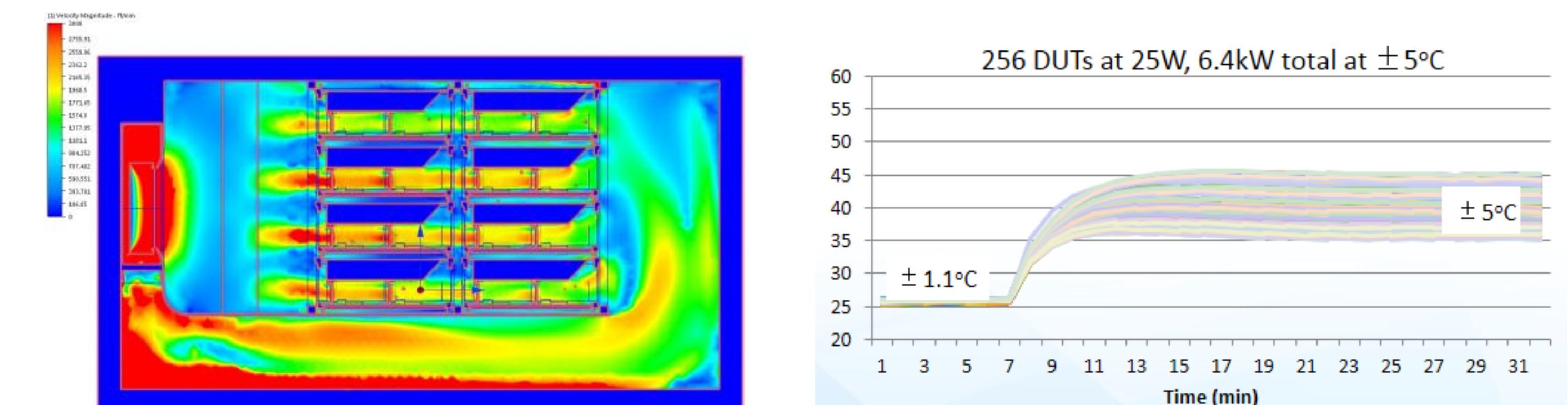
$$t_f = A e^{E_A/kT}$$

Arrhenius Equation

(Temperature Dependent Time to Fail)

$t_f$ : time to fail  $A$ : acceleration factor  $E_A$ : activation energy;

$T$ : temperature  $k$ : Boltzmann's constant



Active Cooling for Endurance, Closed-loop Ambient for Production